

To our customers,

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## Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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P-CHANNEL MOS FIELD EFFECT TRANSISTOR  
FOR SWITCHING

DESCRIPTION

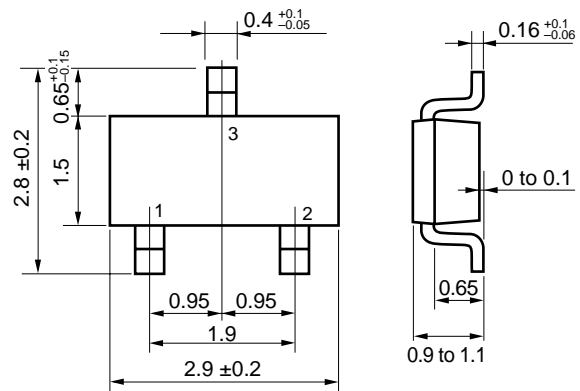
The 2SJ624 is a switching device which can be driven directly by a 1.8 V power source.

This device features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- 1.8 V drive available
- Low on-state resistance  
 $R_{DS(on)1} = 54 \text{ m}\Omega \text{ MAX. (} V_{GS} = -4.5 \text{ V, } I_D = -2.5 \text{ A)}$   
 $R_{DS(on)2} = 71 \text{ m}\Omega \text{ MAX. (} V_{GS} = -2.5 \text{ V, } I_D = -2.5 \text{ A)}$   
 $R_{DS(on)3} = 108 \text{ m}\Omega \text{ MAX. (} V_{GS} = -1.8 \text{ V, } I_D = -1.5 \text{ A)}$

PACKAGE DRAWING (Unit: mm)



1 : Gate  
2 : Source  
3 : Drain

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SJ624	SC-96 (Mini Mold Thin Type)

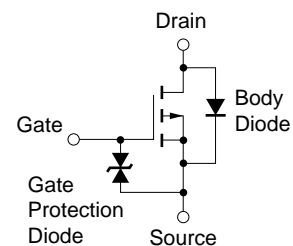
Marking: XH

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

Drain to Source Voltage ( $V_{GS} = 0 \text{ V}$ )	$V_{DSS}$	-20	V
Gate to Source Voltage ( $V_{DS} = 0 \text{ V}$ )	$V_{GSS}$	$\pm 8.0$	V
Drain Current (DC) ( $T_A = 25^\circ\text{C}$ )	$I_{D(DC)}$	$\pm 4.5$	A
Drain Current (pulse) <sup>Note1</sup>	$I_{D(pulse)}$	$\pm 18$	A
Total Power Dissipation	$P_{T1}$	0.2	W
Total Power Dissipation <sup>Note2</sup>	$P_{T2}$	1.25	W
Channel Temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

- Notes 1.  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$   
2. Mounted on FR-4 board,  $t \leq 5 \text{ sec.}$

EQUIVALENT CIRCUIT



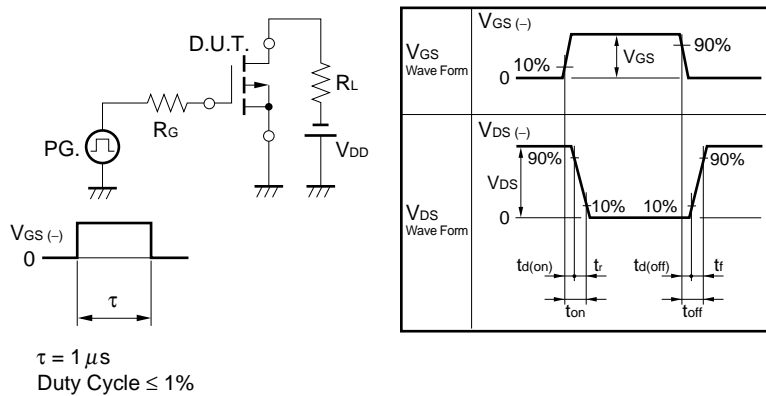
**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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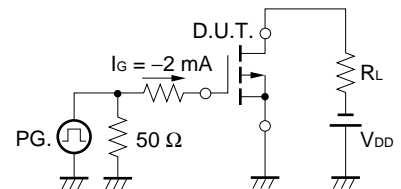
**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)**

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = -20 V, V <sub>GS</sub> = 0 V			-10	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±8.0 V, V <sub>DS</sub> = 0 V			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1.0 mA	-0.45	-0.75	-1.5	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -2.5 A	5.0	9.5		S
Drain to Source On-state Resistance	R <sub>DS(on)1</sub>	V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -2.5 A		43	54	mΩ
	R <sub>DS(on)2</sub>	V <sub>GS</sub> = -2.5 V, I <sub>D</sub> = -2.5 A		53	71	mΩ
	R <sub>DS(on)3</sub>	V <sub>GS</sub> = -1.8 V, I <sub>D</sub> = -1.5 A		65	108	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -10 V		813		pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V		165		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1.0 MHz		69		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = -10 V, I <sub>D</sub> = -2.5 A		14		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = -4.0 V		42		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		80		ns
Fall Time	t <sub>f</sub>			92		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = -16 V		8.1		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = -4.0 V		1.3		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = -4.5 A		2.8		nC
Body Diode Forward Voltage	V <sub>F(S-D)</sub>	I <sub>F</sub> = 4.5 A, V <sub>GS</sub> = 0 V		0.90		V

**TEST CIRCUIT 1 SWITCHING TIME**

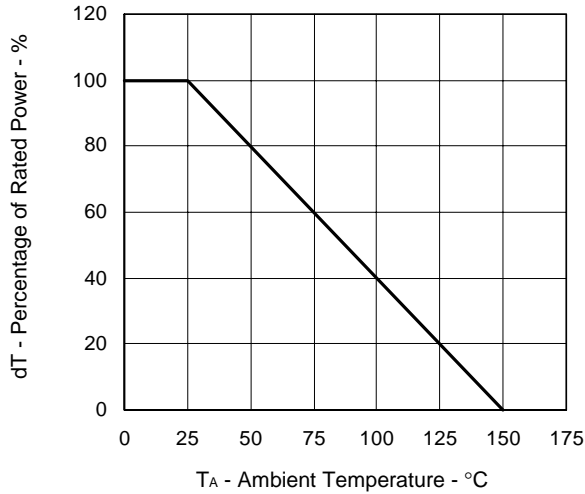


**TEST CIRCUIT 2 GATE CHARGE**

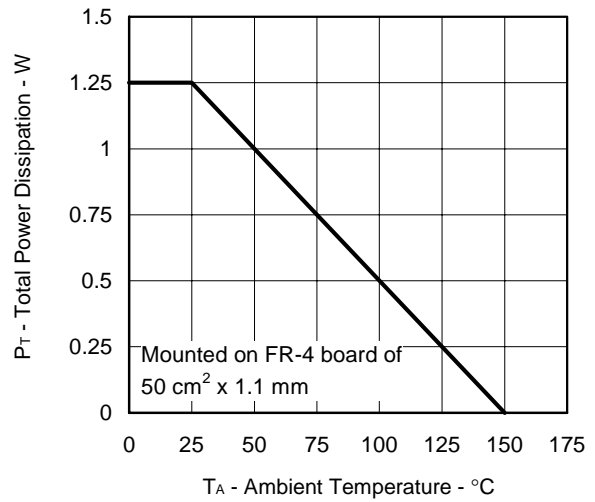


TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

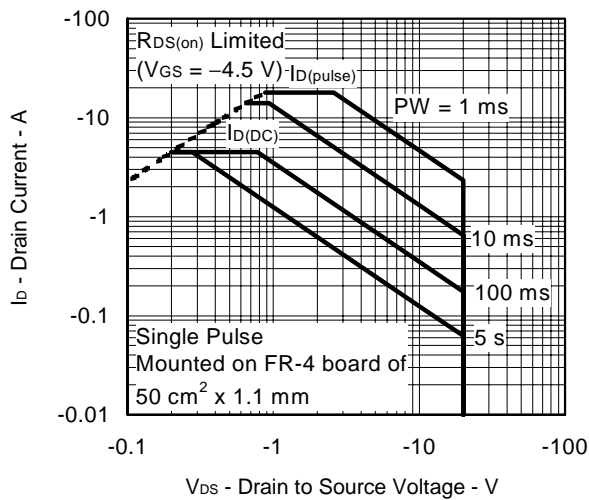
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



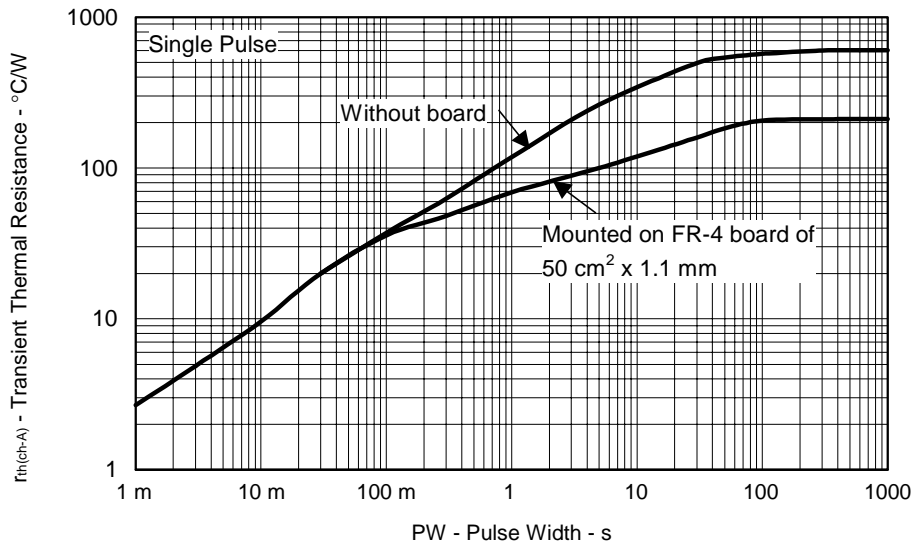
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



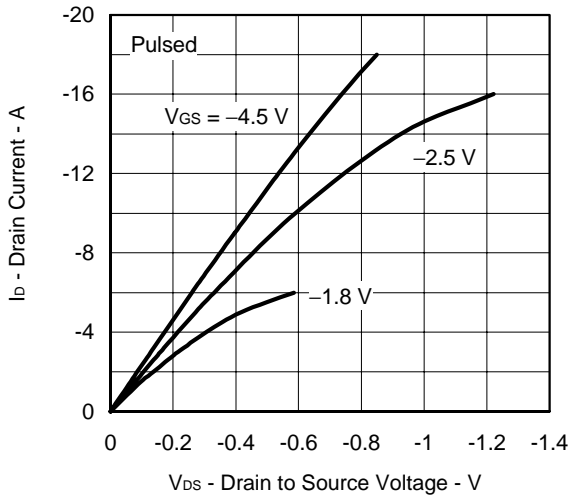
FORWARD BIAS SAFE OPERATING AREA



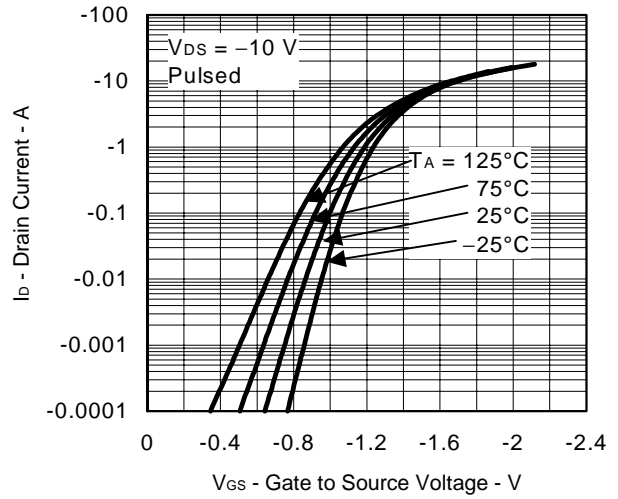
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



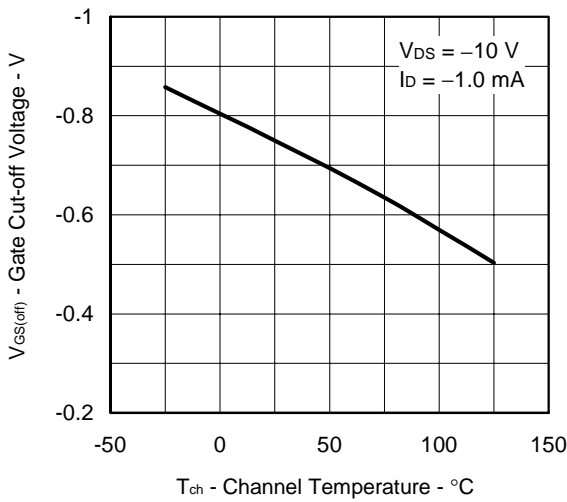
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



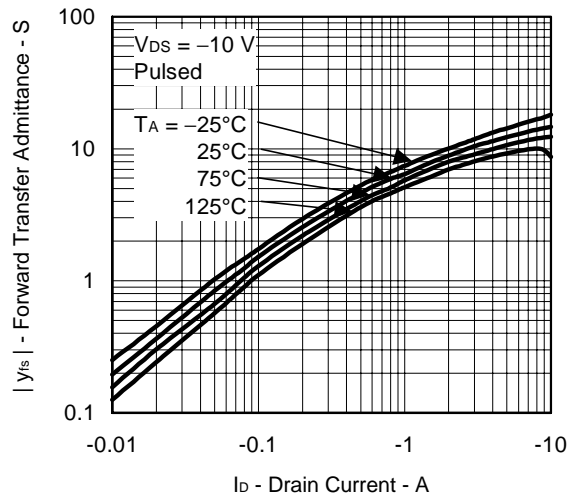
FORWARD TRANSFER CHARACTERISTICS



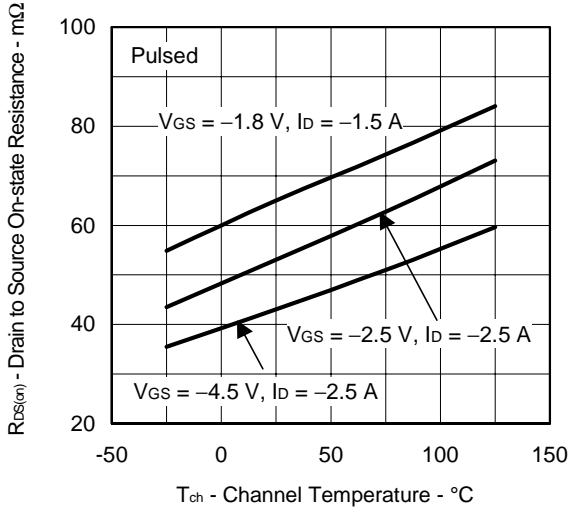
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



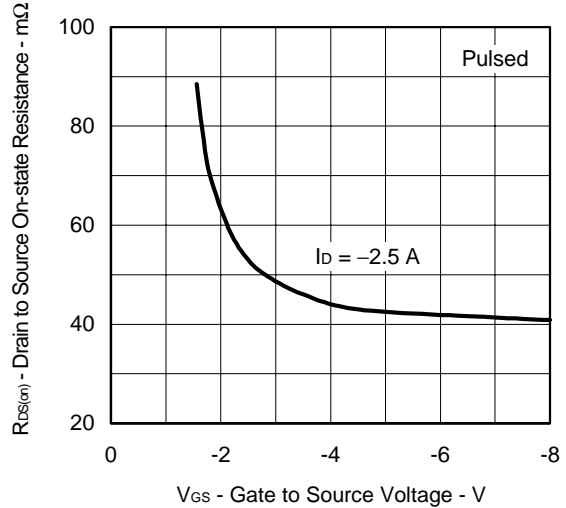
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



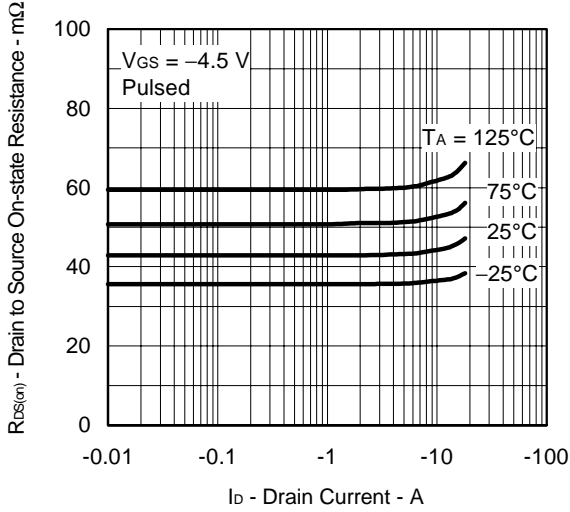
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



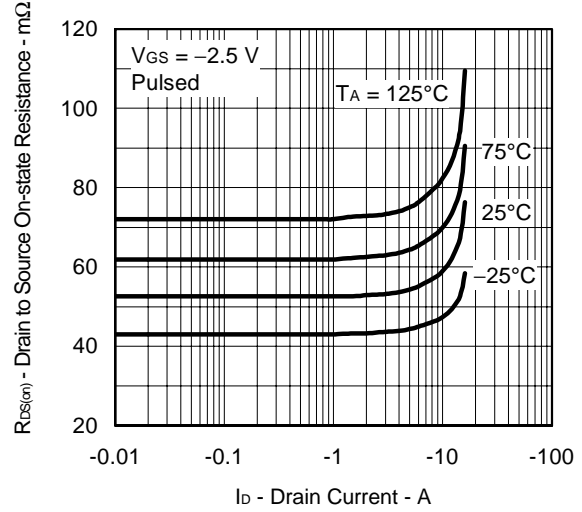
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



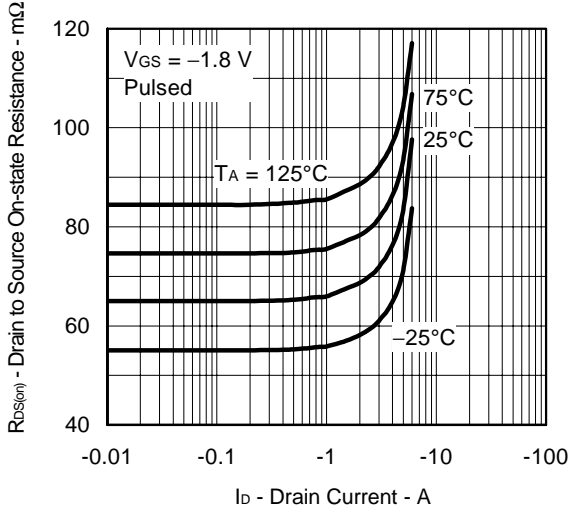
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



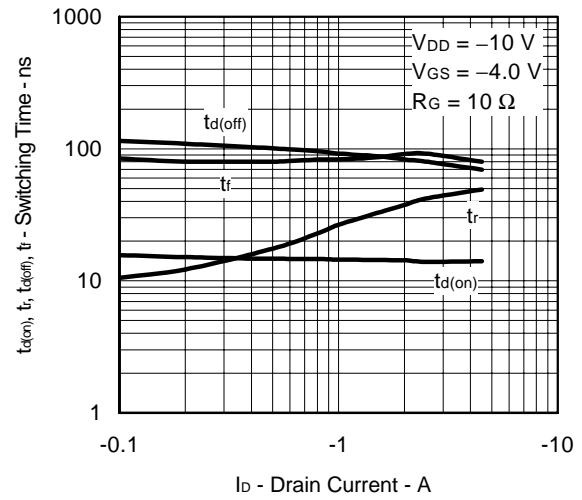
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



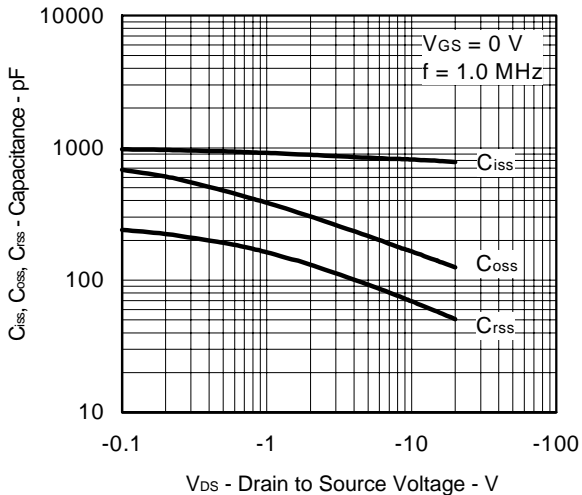
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



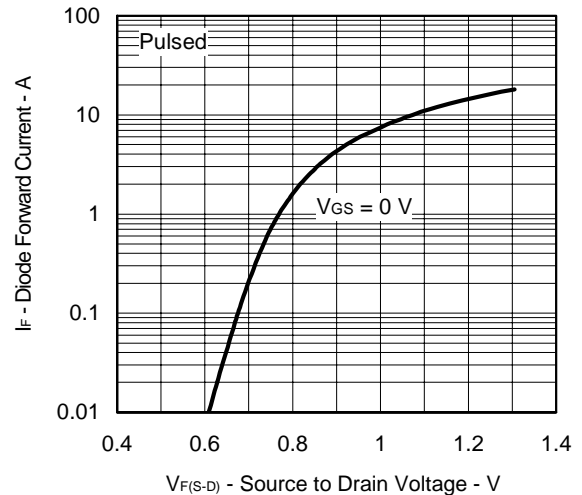
SWITCHING CHARACTERISTICS



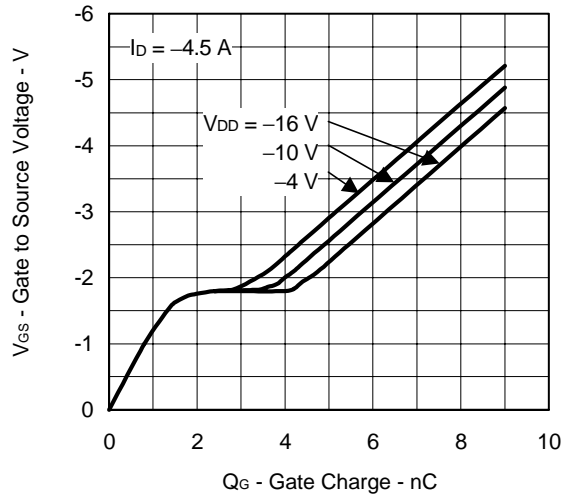
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS





[MEMO]

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